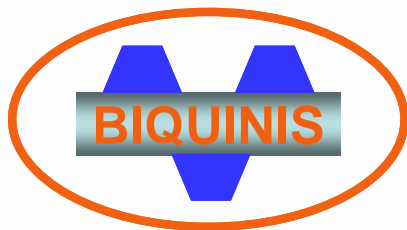


Columnar quantum dots (QD) in polarization insensitive SOA and non-radiative Auger processes in QD: a theoretical study

J. Even, L. Pedesseau, F. Doré, *S. Boyer-Richard*,

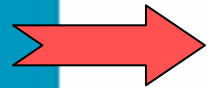
UMR FOTON 6082 CNRS, INSA de Rennes, France

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Supported by the French ANR project BIQUINIS

8th International Conference on Numerical Simulation of Optoelectronic Devices, Nottingham, 4th September 2008

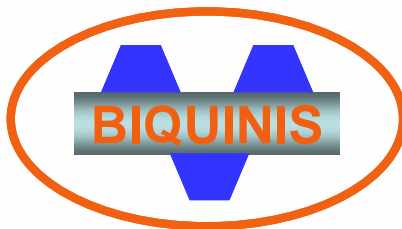


I- k.p axial approximation

*II- Columnar quantum dots (QD) in
polarization insensitive semiconductor
optical amplifiers (SOA)*

III- Non radiative Auger process in QD

IV- Conclusion



Geometry of quantum dot : $C_{\infty v}$ symmetry



A new description in
cylindrical
coordinates : r, φ, z

Some references for k.p axial approximation :

- ¹ P. Enders and M. Woerner, SST (1996) : **k-dependent 4x4 block-diag. of 8x8 Ham. (Bulk)**
- ² C. Y. P. Chao and S. L. Chuang, PRB (1992) : **k-ind. block-diag. of 6x6 Ham. (QW)**
- ³ Y. M. Mu and S. S. Pei, JAP (2004) : **k-ind. block-diag. of 8x8 Ham. (QW)**
- ⁴ K. J. Vahala and P. C. Sercel, PRL, PRB (1990) : **k-ind. block-diag. of 8x8 Ham. (Qwire and Spherical QD)**
- ⁵ M. Tadic, F.M. Peeters and K. J. Janssens, JAP, PRB (2002, 2004) **k-ind. block-diag. of 6x6 Ham. (QD)**

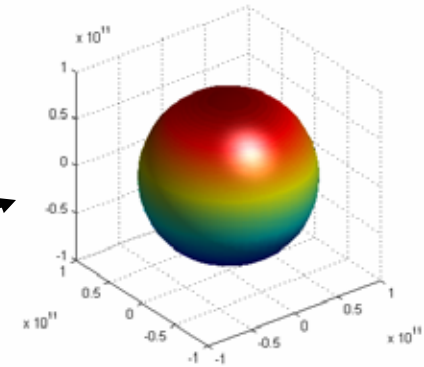
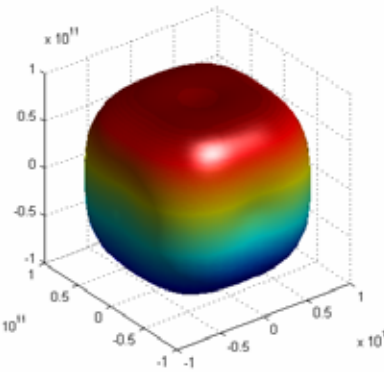
Acoustic phonon band “warping” in cubic materials

A test : → sound velocities in InAs

Surfaces : angular dependence of the longitudinal velocity

Even et al, APL (2007) P04-P12

Cubic material

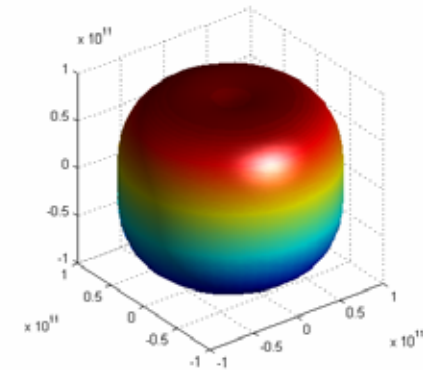
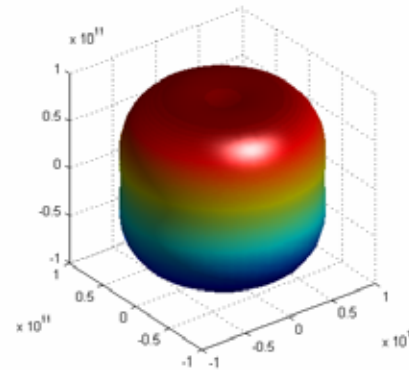
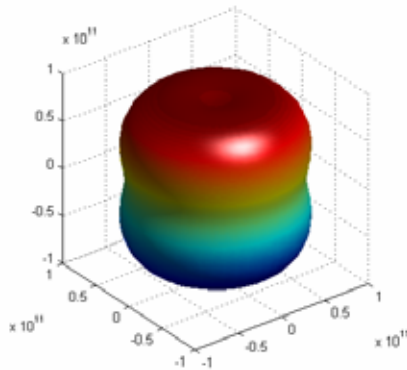


“3D isotropic” approx.

$d = 0$

$d = 0.5$

$d = 1$



“Transverse isotropic” approx.
$$\bar{C} = \frac{C_{11} - C_{12}}{2} + \left(C_{44} - \frac{C_{11} - C_{12}}{2} \right) d$$

Description in cylindrical coordinates : $r, \phi, z \longrightarrow \epsilon_{rr}, \epsilon_{\phi\phi}, \epsilon_{zz}, \epsilon_{rz}$

“Transverse isotropic” approx. for cubic materials

$$\begin{pmatrix} C'_{11} & C'_{12} & C_{12} & 0 & 0 & 0 \\ C'_{12} & C'_{11} & C_{12} & 0 & 0 & 0 \\ C_{12} & C_{12} & C'_{11} & 0 & 0 & 0 \\ 0 & 0 & 0 & C_{44} & 0 & 0 \\ 0 & 0 & 0 & 0 & C_{44} & 0 \\ 0 & 0 & 0 & 0 & 0 & \bar{C} \end{pmatrix}$$

$$C'_{11} = \frac{C_{11} + C_{12}}{2} + \bar{C}$$

$$C'_{12} = \frac{C_{11} + C_{12}}{2} - \bar{C}$$

4 parameters

Back to cartesian coordinates

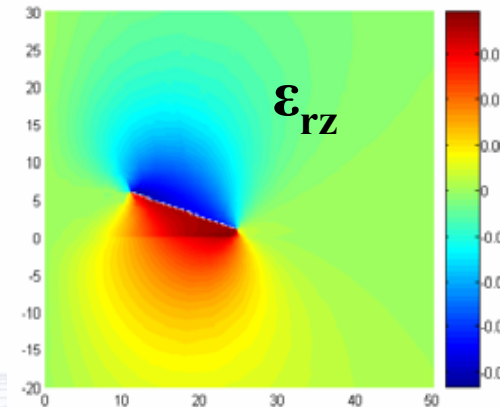
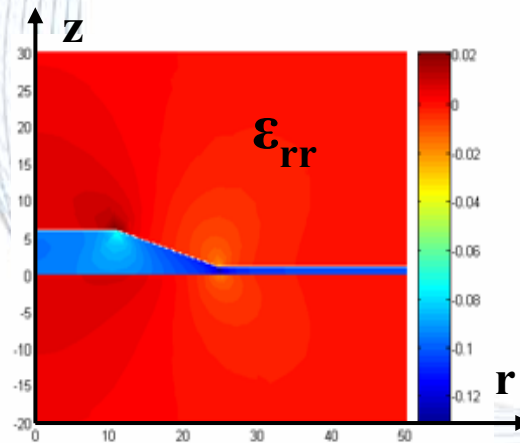


$$\begin{aligned} \epsilon_{xx} &= \cos^2(\phi)\epsilon_{rr} + \sin^2(\phi)\epsilon_{\phi\phi} \\ \epsilon_{yy} &= \sin^2(\phi)\epsilon_{rr} + \cos^2(\phi)\epsilon_{\phi\phi} \end{aligned}$$

$$\begin{aligned} \epsilon_{xz} &= \cos(\phi)\epsilon_{rz} \\ \epsilon_{yz} &= \sin(\phi)\epsilon_{rz} \end{aligned}$$

$$\epsilon_{xy} = \frac{\sin(2\phi)}{2}(\epsilon_{rr} - \epsilon_{\phi\phi})$$

Example : InAs/GaP QD



Unstrained part :

$$R = -\sqrt{3} \frac{\hbar^2}{2m_0} [\gamma_2 (k_x^2 - k_y^2) - 2i\gamma_3 k_x k_y] \approx -\sqrt{3} \frac{\hbar^2}{2m_0} \bar{\gamma} k_-^2$$

**Strained part :
(new proposition)**

$$R_\varepsilon = \frac{b\sqrt{3}}{2} (\varepsilon_{rr} - \varepsilon_{\varphi\varphi}) \cos(2\varphi) - i \frac{d}{2} (\varepsilon_{rr} - \varepsilon_{\varphi\varphi}) \sin(2\varphi) \approx \frac{\bar{b}\sqrt{3}}{2} (\varepsilon_{rr} - \varepsilon_{\varphi\varphi}) e^{-i2\varphi}$$



$$\frac{\bar{b}\sqrt{3}}{2} = \frac{1}{2} \left(\frac{b\sqrt{3}}{2} + \frac{d}{2} \right) \left\{ \begin{array}{l} \text{InAs} \quad \frac{b\sqrt{3}}{2} = -1.58eV \quad \frac{d}{2} = -1.80eV \\ \text{GaAs} \quad \frac{b\sqrt{3}}{2} = -1.56eV \quad \frac{d}{2} = -2.25eV \\ \text{InP} \quad \frac{b\sqrt{3}}{2} = -1.73eV \quad \frac{d}{2} = -2.50eV \end{array} \right.$$

Even et al, PRB (2008)

$$A_\varepsilon = a_c (\varepsilon_{rr} + \varepsilon_{\varphi\varphi} + \varepsilon_{zz})$$

$$P_\varepsilon = a_v (\varepsilon_{rr} + \varepsilon_{\varphi\varphi} + \varepsilon_{zz})$$

Hydrostatic strain

$$Q_\varepsilon = b \left(\varepsilon_{zz} - \frac{\varepsilon_{rr} + \varepsilon_{\varphi\varphi}}{2} \right)$$

Biaxial strain

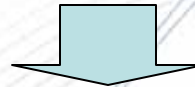
$$R_\varepsilon = \frac{\bar{b}\sqrt{3}}{2} (\varepsilon_{rr} - \varepsilon_{\varphi\varphi}) e^{-i2\varphi}$$

$$S_\varepsilon = -d \varepsilon_{rz} e^{-i\varphi}$$

Shear strain

Block diagonalization of the Hamiltonian for each F_z value :

A good quantum number : total angular momentum $F_z = J_z + L_z$



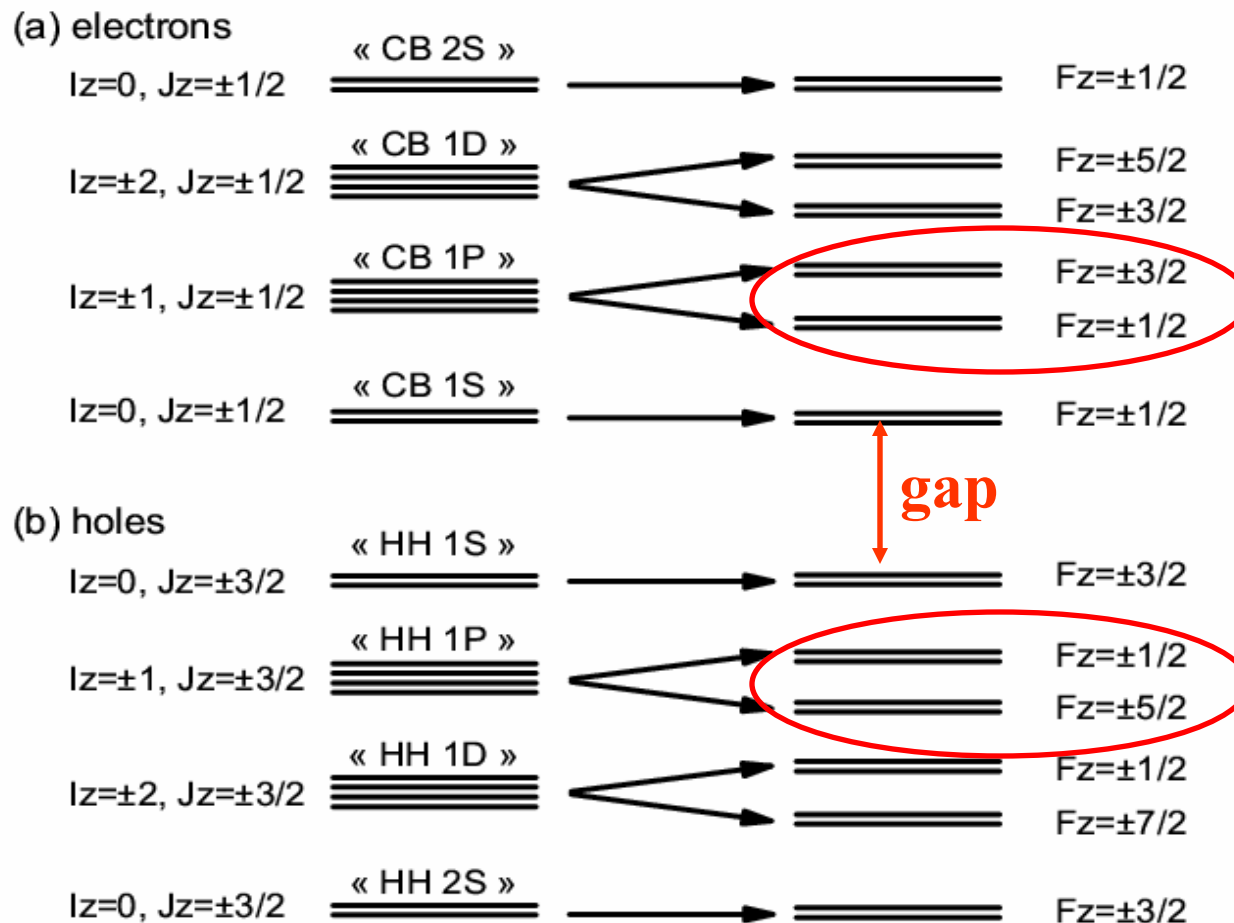
Development of the wavefunction : $|J, J_z\rangle |L_z = F_z - J_z\rangle$

Basis of 8 Bloch functions u_i ($i=1\dots 8$)

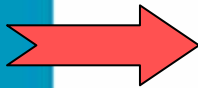
8 envelope functions of (r, z)

J_z	F_z	-5/2	-3/2	-1/2	1/2	3/2	5/2
1/2	L_{z1}	-2	-1	0	+1	+2	+3
-1/2	L_{z2}	-3	-2	-1	0	+1	+2
-1/2	L_{z3}	-3	-2	-1	0	+1	+2
-3/2	L_{z4}	-4	-3	-2	-1	0	+1
3/2	L_{z5}	-1	0	+1	+2	+3	+4
1/2	L_{z6}	-2	-1	0	+1	+2	+3
1/2	L_{z7}	-2	-1	0	+1	+2	+3
-1/2	L_{z8}	-3	-2	-1	0	+1	+2

Excited “p” and “d” states splitting predicted from symmetry analysis



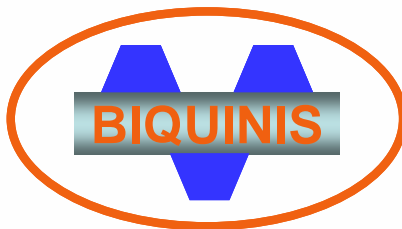
I- $k.p$ axial approximation



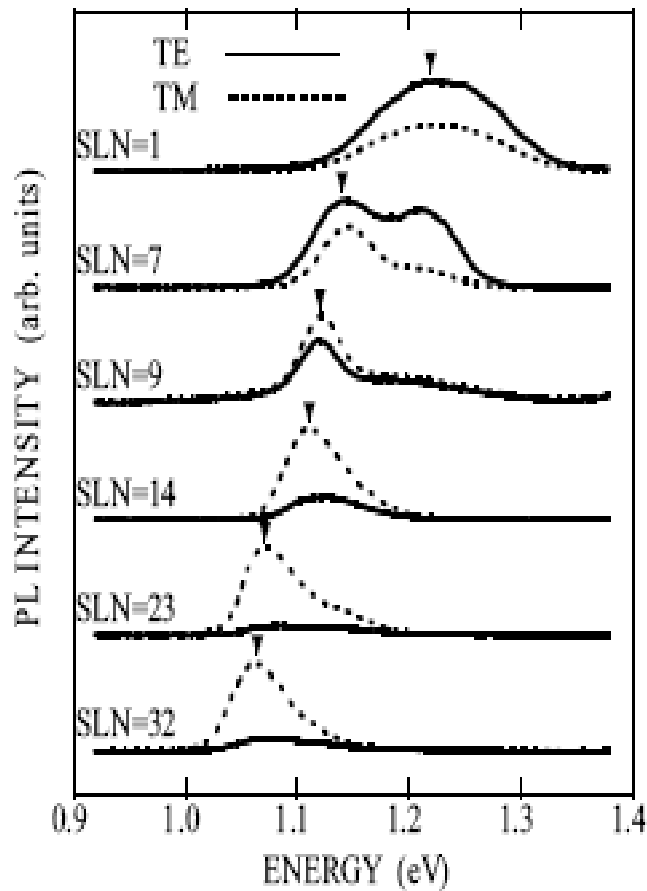
*II- Columnar quantum dots (QD) in
polarization insensitive semiconductor
optical amplifiers (SOA)*

III- Non radiative Auger process in QD

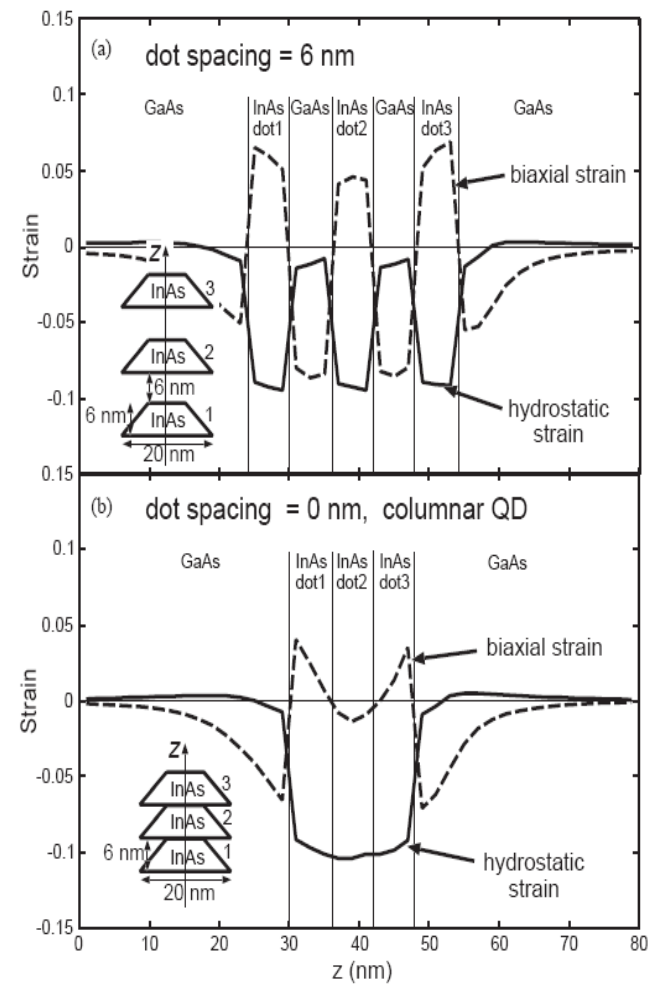
IV- Conclusion



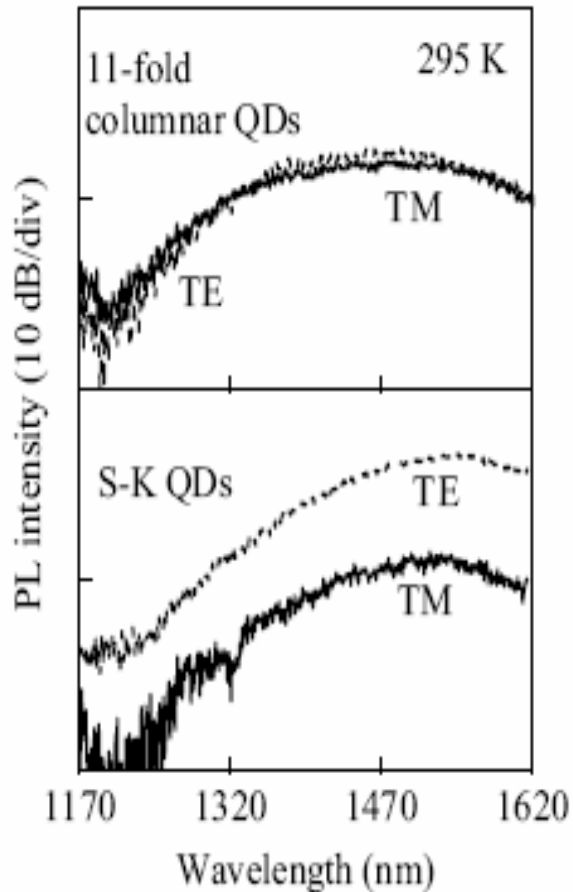
InAs/GaAs



Kita, Phys. Stat. Sol. (2003)



Saito, Physica E (2005)



InAs/InP

Transitions between 2 states F_{z1}/F_{z2}

TE absorption :

$$\Delta F = |F_{z1} - F_{z2}| = \pm 1$$

TM absorption :

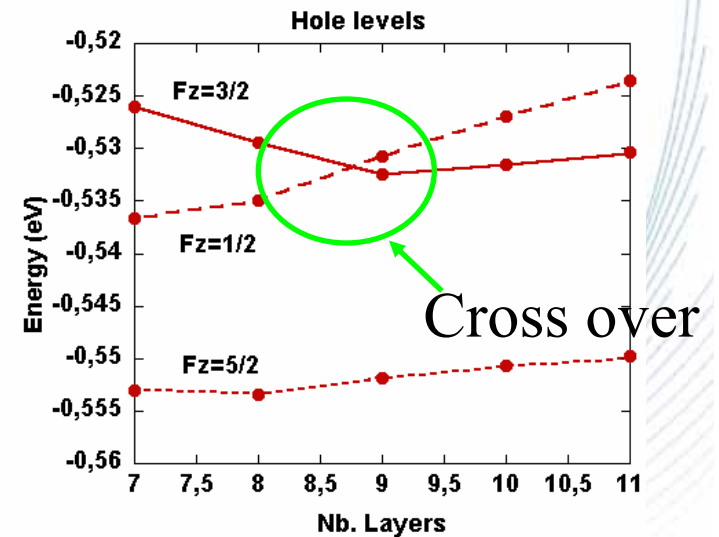
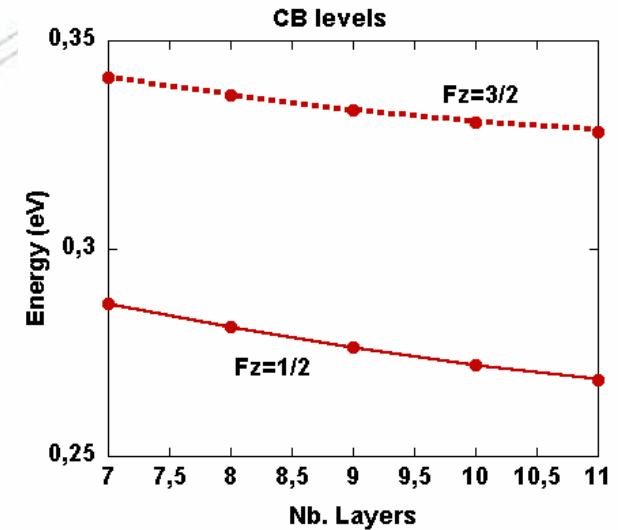
$$\Delta F = |F_{z1} - F_{z2}| = 0$$

In 1 QD :

Electron GS : $F_Z = \pm 1/2$,

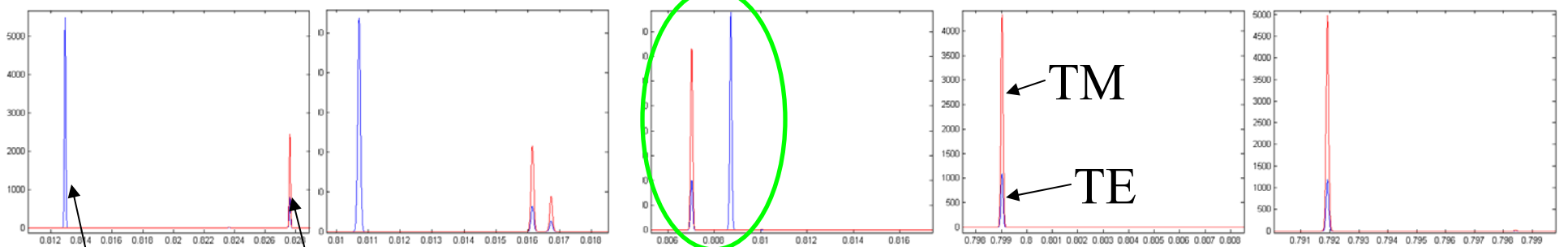
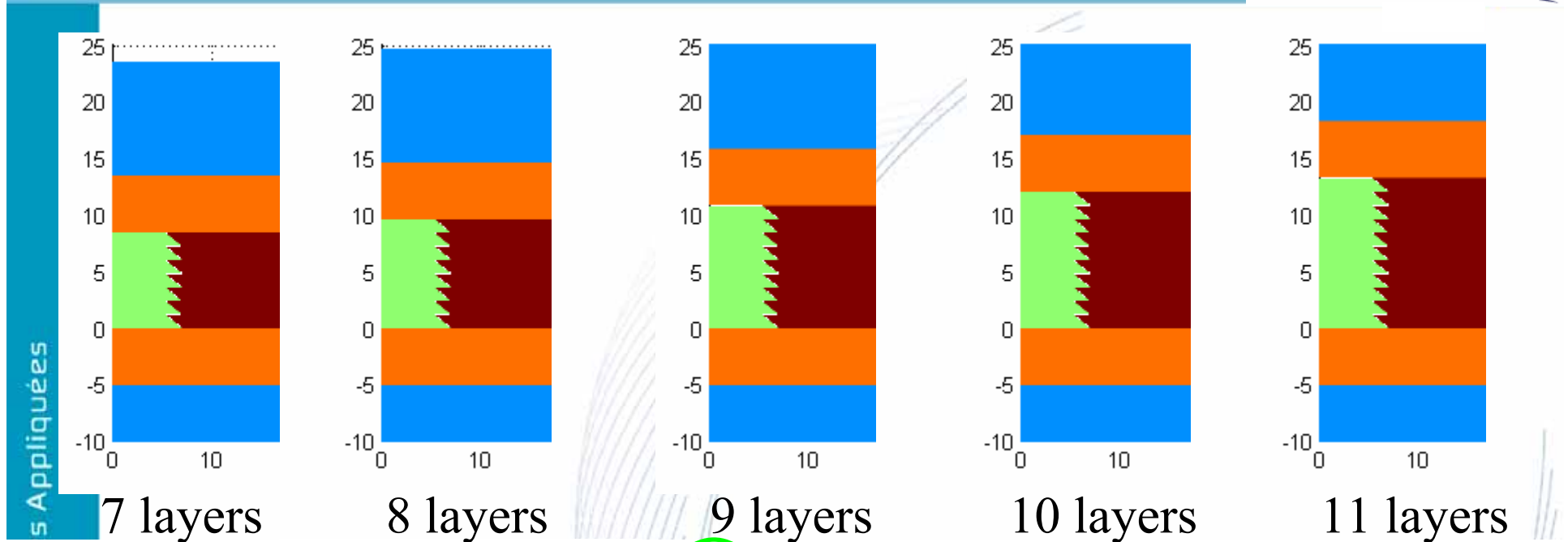
Hole GS : $F_Z = \pm 3/2$

TE transitions



Kawagushi, Phys. Stat. Sol. (2006)

This model

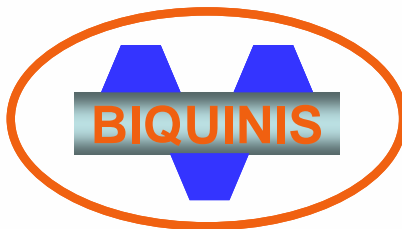


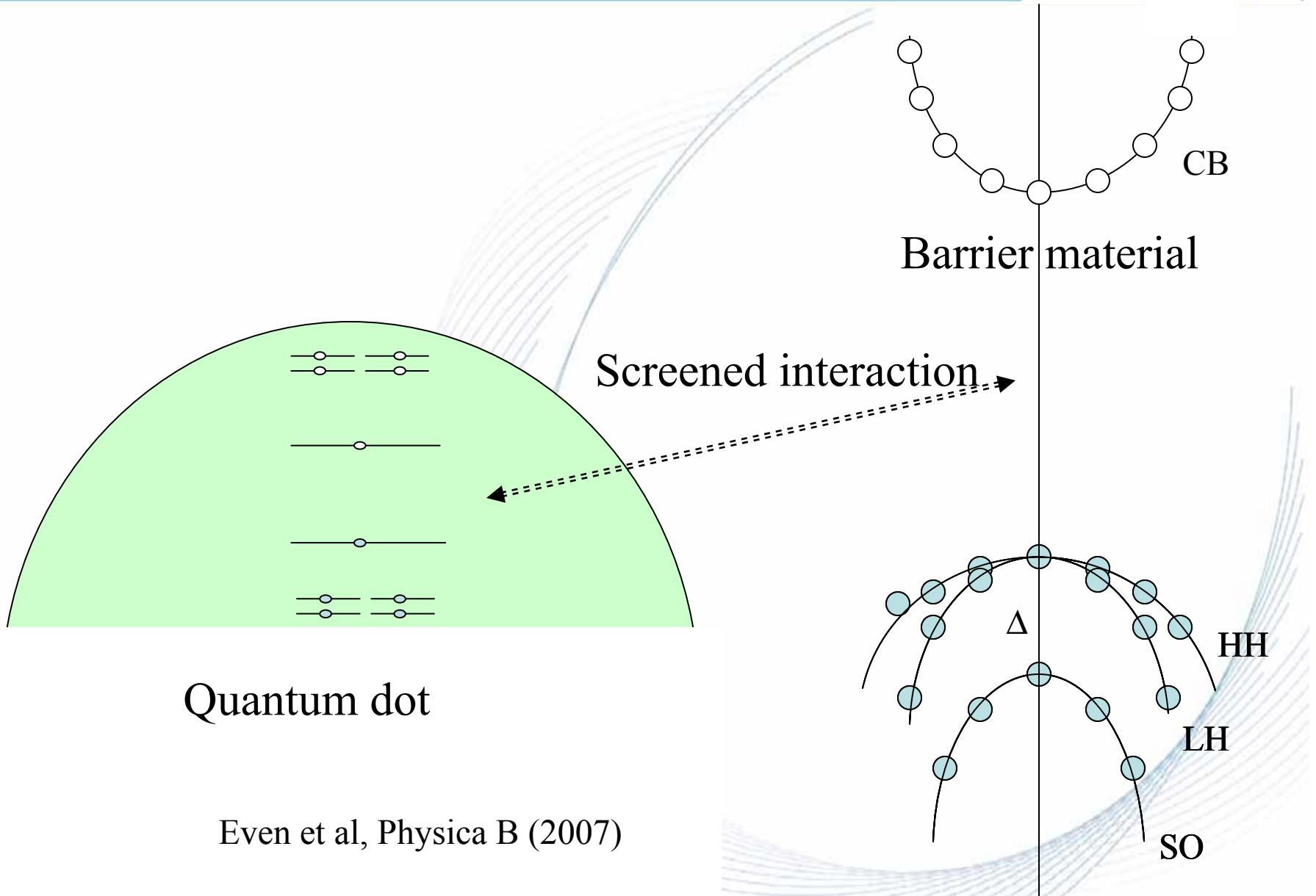
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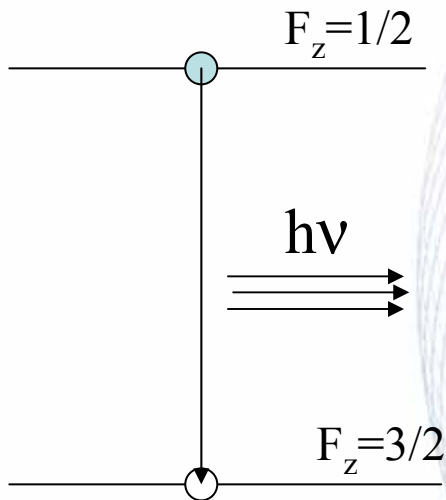
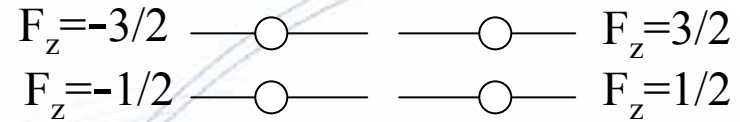
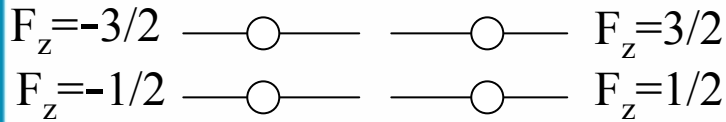
IV- Conclusion



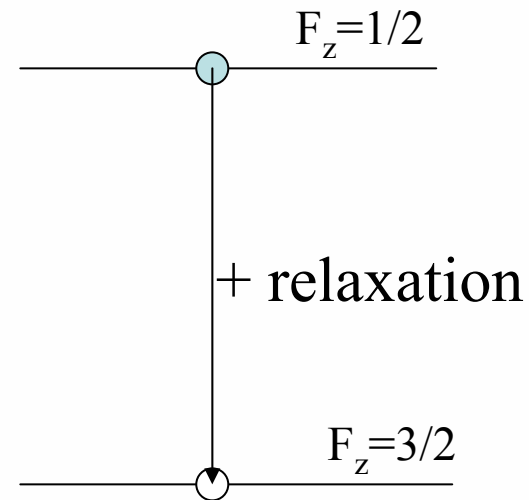


Quantum dot

Even et al, Physica B (2007)

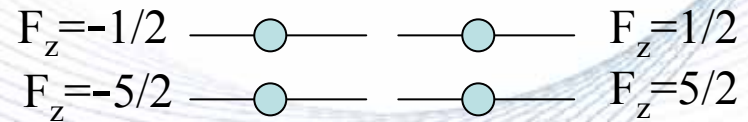
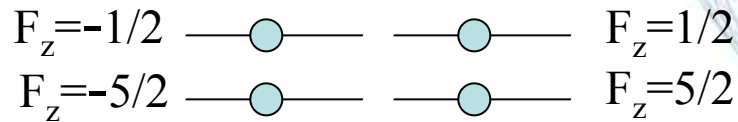


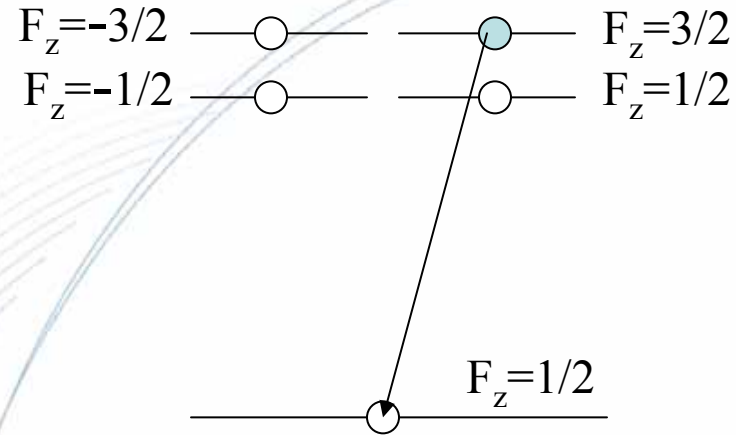
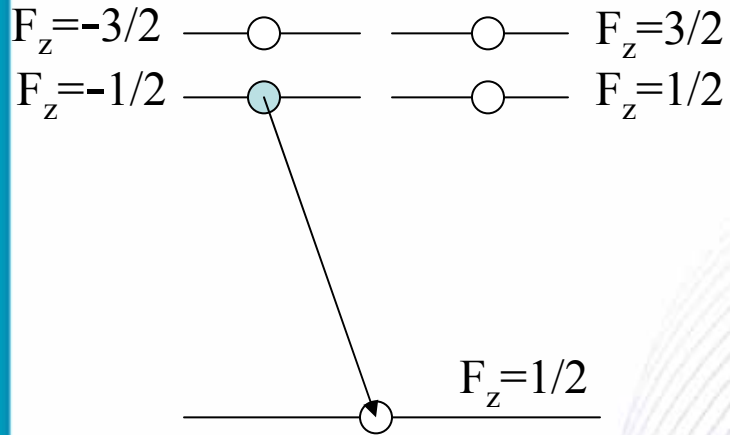
(C-H)



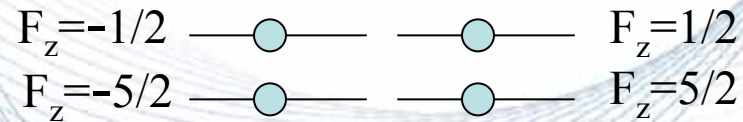
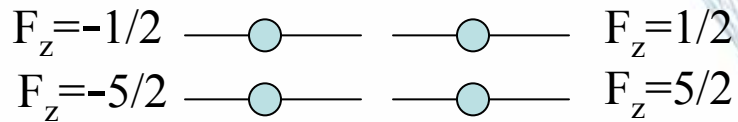
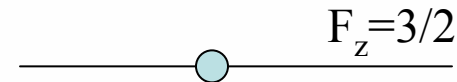
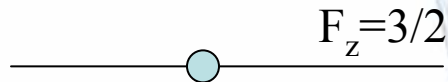
Radiative process in QD

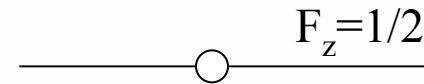
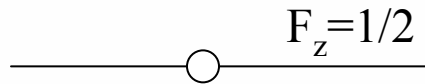
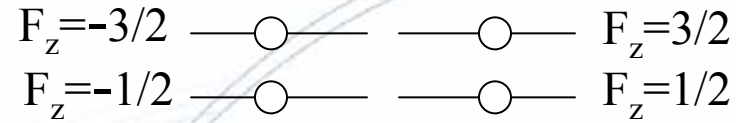
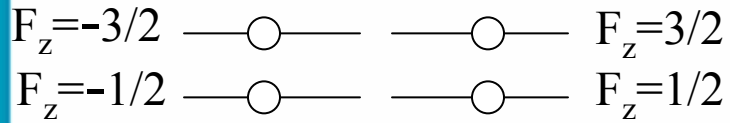
Non-radiative process in QD



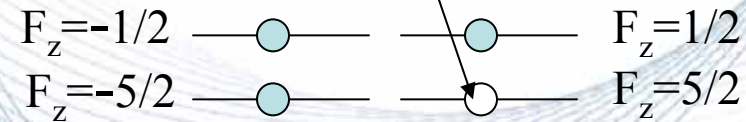
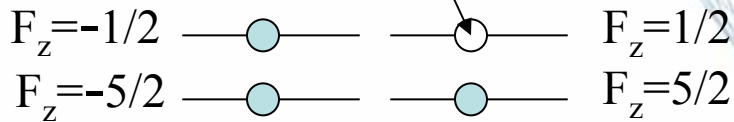
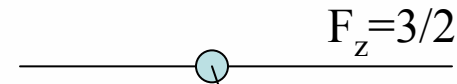
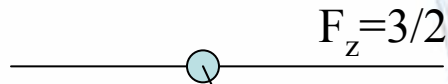


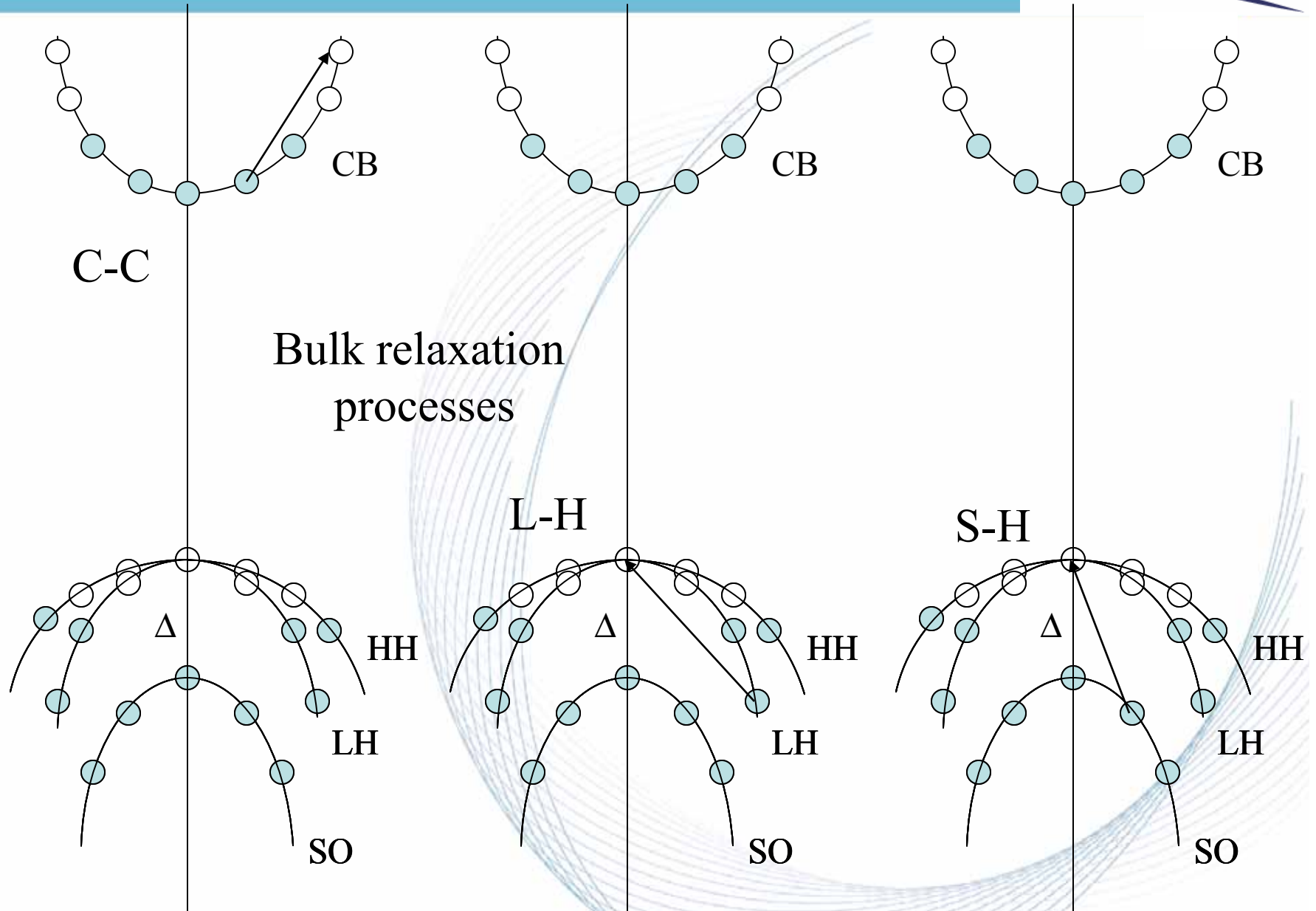
CB relaxation in QD (C-C)

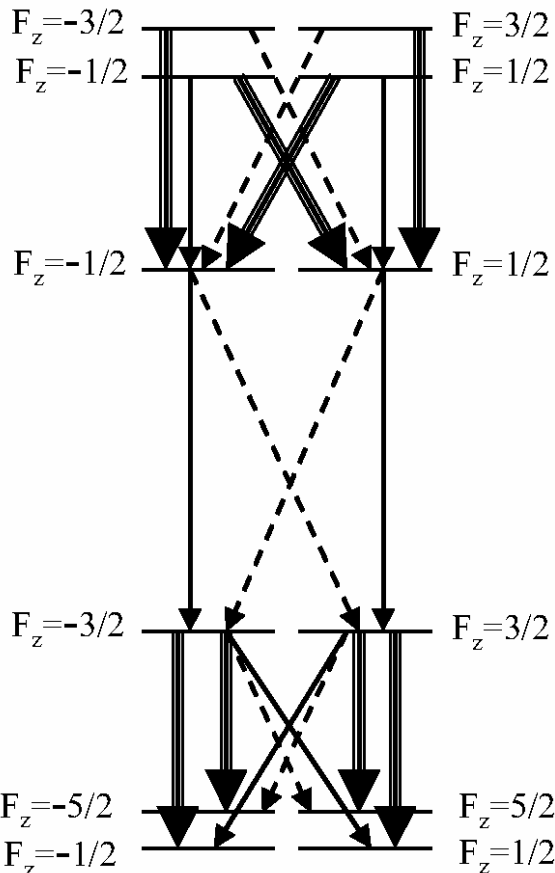




Hole relaxation in QD (H-H)







Example : InAs/Q1.18/InP truncated cone QD

$E_{CH}=0.77\text{eV}$ (gap) $E_{CC}=23\text{meV}$ $E_{HH}=16\text{meV}$
 $N_{\text{Bulk}}=10^{18}\text{cm}^{-3}$

Non-radiative processes :

$\tau_{CHCC}=0.2\mu\text{s}$ $\tau_{CHLH}=1.1\text{ms}$ $\tau_{CHSH}=14\text{ns}$

CB relaxation in QD :

$\tau_{CCCC}=0.74\text{ps}$ $\tau_{CCLH}=24\text{ps}$ $\tau_{CCSH}=\infty$

Hole relaxation in QD :

$\tau_{HHCC}=1.0\text{ps}$ $\tau_{HHLH}=22\text{ps}$ $\tau_{HHSB}=\infty$

Conclusion : further studies...

- **New axially symmetric strained nanostructures**
- **Auger effects (gap influence, comparison WL/bulk, barrier materials, hydrostatic pressure...)**
- **Beyond the 8-band k.p approximation**